

# DVIULC6-2x6

# Ultra low capacitance ESD protection

## Features

- 2-line ESD protection (at 15 kV air and contact discharge, exceeds IEC 61000-4-2)
- Protects V<sub>BUS</sub> when applicable
- Ultra low capacitance: 0.6 pF at F = 825 MHz
- Fast response time compared with varistors
- Low leakage current: 0.5 µA max
- RoHS compliant

#### **Benefits**

- ESD standards compliance guaranteed at device level, hence greater immunity at system level
- ESD protection of V<sub>BUS</sub> when applicable.
- Large bandwidth to minimize impact on data signal quality
- Consistent D+ / D- signal balance:
  - Ultra low impact on intra- and inter-pair skew
  - Matching high bit rate DVI, and IEEE 1394 requirements
- Low PCB space consumption 1.45 mm<sup>2</sup> for µQFN
- Low leakage current for longer operation of battery powered devices
- Higher reliability offered by monolithic integration
- 500 µm pitch for µQFN 6 leads

#### **Complies with these standards**

- IEC 61000-4-2 level 4
  - 15 kV air discharge
  - 8 kV contact discharge
- MIL STD883G-Method 3015-7



µQFN (pin view) DVIULC6-2M6



SOT-666 DVIULC6-2P6

# Applications

- DVI ports up to 1.65 Gb/s
- IEEE 1394a, b, and c up to 3.2 Gb/s
- USB2.0 ports up to 480 Mb/s (high speed), backwards compatible with USB1.1 low and full speed
- Ethernet port: 10/100/1000 Mb/s
- SIM card protection
- Video line protection

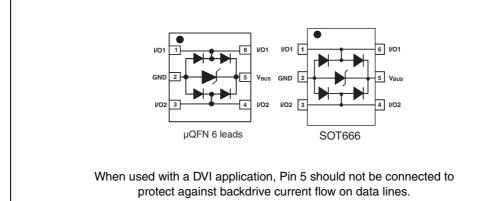
### Description

The **DVIULC6-2x6** is a monolithic, application specific discrete device dedicated to ESD protection of high speed interfaces, such as DVI, IEEE 1394a, b and c, USB2.0, Ethernet links and video lines.

Its ultra low line capacitance secures a high level of signal integrity without compromising in protecting sensitive chips against the most stringently characterized ESD strikes.

# 1 Characteristics





#### Table 1.Absolute ratings

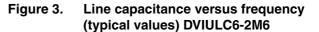
Symbol	Pa	Value	Unit	
V <sub>PP</sub>	Peak pulse voltage IEC61000-4-2 air discharge IEC61000-4-2 contact discharge MIL STD883G-Method 3015-7		±15 ±15 ±25	kV
T <sub>stg</sub>	Storage temperature range	-55 to +150	°C	
Тj	Maximum junction temperatu	125	°C	
TL	Lead solder temperature (10	260	°C	

# Table 2.Electrical characteristics ( $T_{amb} = 25 \ ^{\circ}C$ )

Symbol	Parameter Test Conditions		Value			Unit	
Symbol	Falaneter	lest conditions	Min.	Тур.	Max	Unit	
I <sub>RM</sub>	Leakage current	V <sub>RM</sub> = 5 V			0.5	μA	
V <sub>BR</sub>	Breakdown voltage between V <sub>BUS</sub> and GND	I <sub>R</sub> = 1 mA	6			۷	
M	Clamping voltage	I <sub>PP</sub> = 1 A, t <sub>p</sub> = 8/20 μs Any I/O pin to GND			12	v	
V <sub>CL</sub> Clamping voltage	Clamping voltage	$I_{PP} = 5 \text{ A}, t_p = 8/20 \mu\text{s}$ Any I/O pin to GND			17	V	
C <sub>i/o-GND</sub>	Capacitance between I/O and GND	$V_{R} = 0 V$ , F= 825 MHz			0.85	pF	
$\Delta C_{i/o-GND}$	Capacitance variation between I/O and GND	V <sub>R</sub> = 0 V, F= 1 MHz		0.02		pF	
C <sub>i/o-i/o</sub>	Capacitance between I/O	V <sub>R</sub> = 0 V, F= 825 MHz			0.5	pF	



#### Figure 2. Line capacitance versus line voltage (typical values)



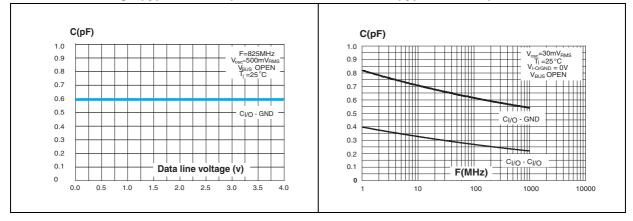
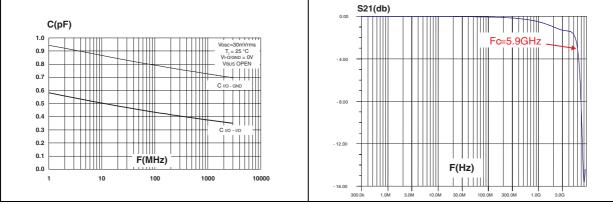


Figure 4. Line capacitance versus frequency Figure 5. (typical values) DVIULC6-2P6

**Frequency response (typical** values) DVIULC6-2M6



Frequency response (typical Figure 6. values) DVIULC6-2P6

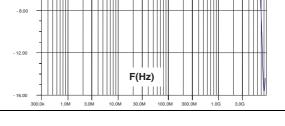
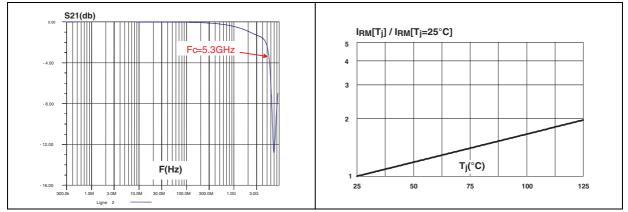


Figure 7. **Relative variation of leakage** current versus junction temperature (typical values)



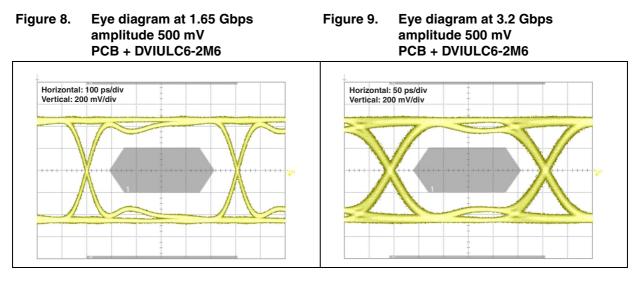
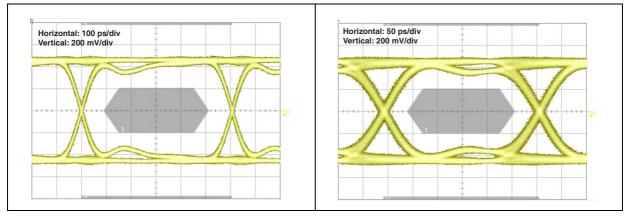


Figure 10. Eye diagram at 1.65 Gbps amplitude 500 mV PCB + DVIULC6-2P6

Figure 11. Eye diagram at 3.2 Gbps amplitude 500 mV PCB + DVIULC6-2P6





# 2 Application examples

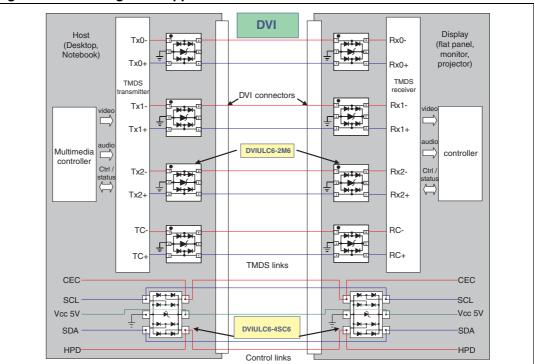
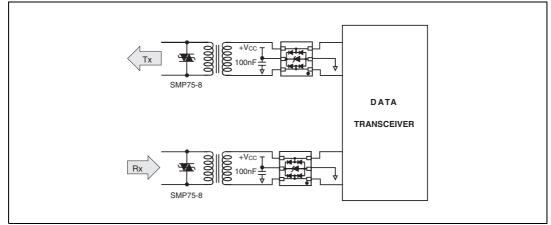




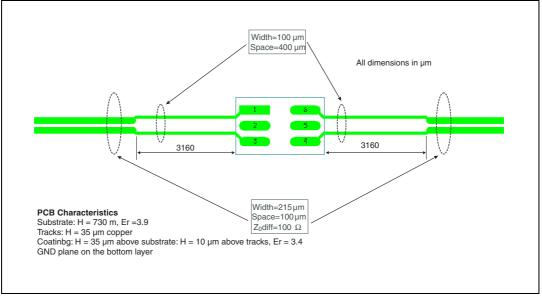
Figure 13. T1/E1/Ethernet protection



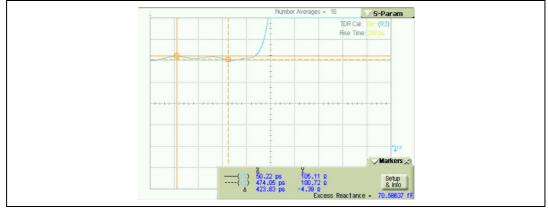
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# 2.1 PCB layout considerations











### **3** Technical information

#### 3.1 Surge protection

The DVIULC6-2x6 is particularly optimized to perform ESD surge protection based on the rail to rail topology.

The clamping voltage  $V_{CL}$  can be calculated as follows:

 $V_{CL}$  + =  $V_{TRANSIL}$  +  $V_{F}$  for positive surges

 $V_{CL}$  = -  $V_F$  for negative surges

with:  $V_F = V_T + R_d I_p$ 

(V<sub>F</sub> forward drop voltage) / (V<sub>T</sub> forward drop threshold voltage)

and  $V_{TRANSIL}$  =  $V_{BR}$  +  $R_{d\_TRANSIL}$  .  $I_{P}$ 

#### Calculation example

We assume that the value of the dynamic resistance of the clamping diode is typically:  $R_d$  = 0.5  $\Omega$  and  $V_T$  = 1.1 V.

We assume that the value of the dynamic resistance of the transil diode is typically  $R_{d_{TRANSIL}} = 0.5 \Omega$  and  $V_{BR} = 6.1 V$ 

For an IEC 61000-4-2 surge Level 4 (Contact Discharge:  $V_g$ = 8 kV,  $R_g$ = 330  $\Omega$ ),  $V_{BUS}$  = +5 V, and, in first approximation, we assume that:  $I_p = V_g / R_g = 24$  A.

We find:

V<sub>CL</sub>+ = +31.2 V V<sub>CL</sub>- = -13.1 V

Note:

The calculations do not take into account phenomena due to parasitic inductances.

### 3.2 Surge protection application example

If we consider that the connections from the pin V<sub>BUS</sub> to V<sub>CC</sub>, from I/O to data line, and from GND to PCB GND plane are two tracks 10 mm long and 0.5 mm wide, we can assume that the parasitic inductances, L<sub>VBUS</sub>, L<sub>I/O</sub>, and L<sub>GND</sub>, of these tracks are about 6 nH. So when an IEC 61000-4-2 surge occurs on the data line, due to the rise time of this spike (tr = 1 ns), the voltage V<sub>CL</sub> has an extra value equal to L<sub>I/O</sub>.dI/dt + L<sub>GND</sub>.dI/dt.

The dl/dt is calculated as: dl/dt = lp/tr = 24 A/ns for an IEC 61000-4-2 surge level 4 (contact discharge  $V_q$  = 8 kV,  $R_q$  = 330  $\Omega$ )

The over voltage due to the parasitic inductances is:  $L_{I/O}$ .dl/dt =  $L_{GND}$ .dl/dt = 6 x 24 = 144 V

By taking into account the effect of these parasitic inductances due to unsuitable layout, the clamping voltage will be:

V<sub>CL</sub>+ = +31.2 + 144 +144 = 319.2 V V<sub>CL</sub>- = -13.1 - 144 -144 = -301.1 V

We can reduce as much as possible these phenomena with simple layout optimization.



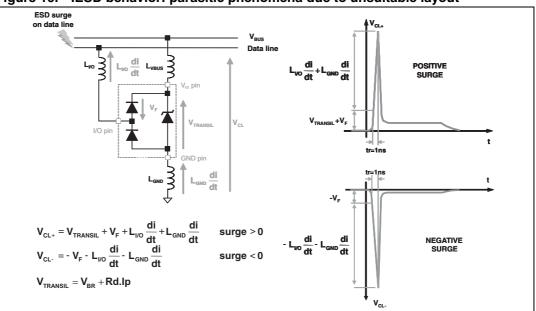
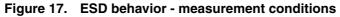
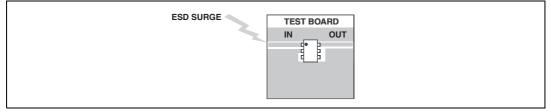
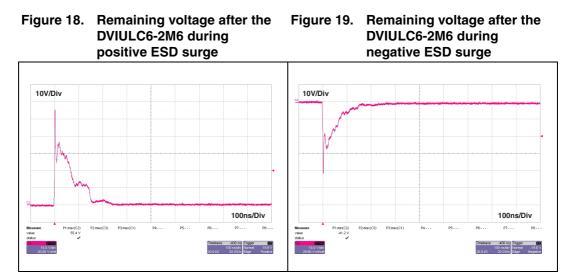


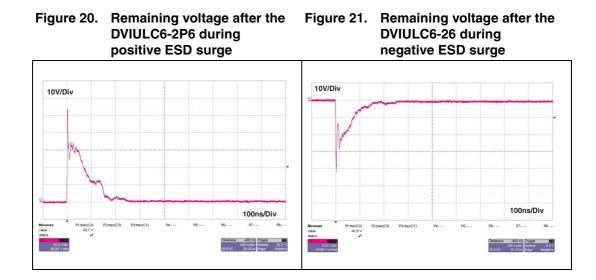
Figure 16. IESD behavior: parasitic phenomena due to unsuitable layout









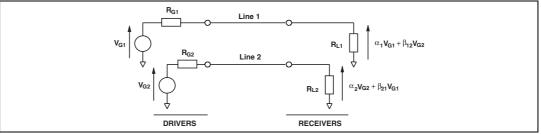


### Important

An important precaution to take is to put the protection device as close as possible to the disturbance source (generally the connector).

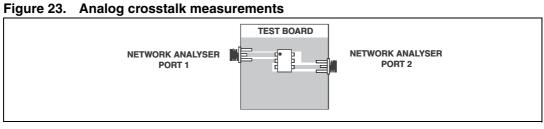
## 3.3 Crosstalk behavior

#### Figure 22. Crosstalk phenomena



The crosstalk phenomena is due to the coupling between 2 lines. The coupling factor ( $\beta_{12}$  or  $\beta_{21}$ ) increases when the gap across lines decreases, particularly in silicon dice. In the example above the expected signal on load  $R_{L2}$  is  $\alpha_2 V_{G2}$ , in fact the real voltage at this point has got an extra value  $\beta_{21}V_{G1}$ . This part of the  $V_{G1}$  signal represents the effect of the crosstalk phenomenon of the line 1 on the line 2. This phenomenon has to be taken into account when the drivers impose fast digital data or high frequency analog signals in the disturbing line. The perturbed line will be more affected if it works with low voltage signal or high load impedance (few k $\Omega$ ).

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*Figure 23* gives the measurement circuit for the analog application. In usual frequency range of analog signals (up to 240 MHz) the effect on disturbed line is less than -40 dB (see *Figure 24*, and *Figure 25*).

Figure 24. Analog crosstalk results (typical values) for DVIULC6-2M6

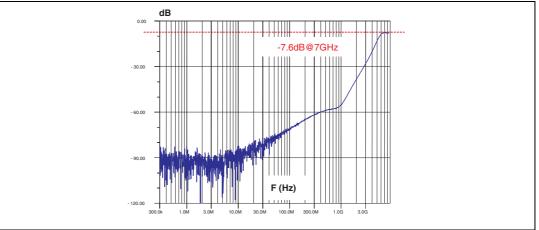
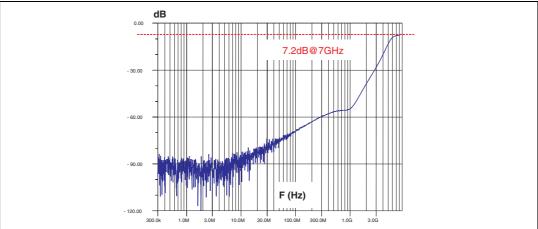


Figure 25. Analog crosstalk results (typical values) for DVIULC6-2P6





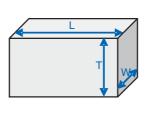
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# 4 **Recommendation on PCB assembly**

### 4.1 Stencil opening design

- 1. General recommendation on stencil opening design
  - a) Stencil opening dimensions: L (Length), W (Width), T (Thickness)

#### Figure 26. Stencil opening dimensions.



b) General Design Rule

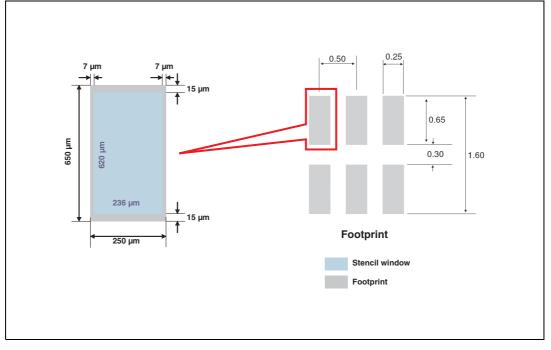
Stencil thickness (T) = 75 ~ 125  $\mu m$ 

Aspect Ratio = 
$$\frac{W}{T} \ge 1.5$$

Aspect Area = 
$$\frac{L \times W}{2T(L+W)} \ge 0.66$$

- 2. Reference design
  - a) Stencil opening thickness: 100 µm
  - b) Stencil opening for leads: Opening to footprint ratio is 90%.

#### Figure 27. Recommended stencil window position (µQFN only)



### 4.2 Solder paste

- 1. Halide-free flux qualification ROL0 according to ANSI/J-STD-004.
- 2. "No clean" solder paste is recommended.
- 3. Offers a high tack force to resist component movement during high speed.
- 4. Solder paste with fine particles: powder particle size is 20-45  $\mu$ m.

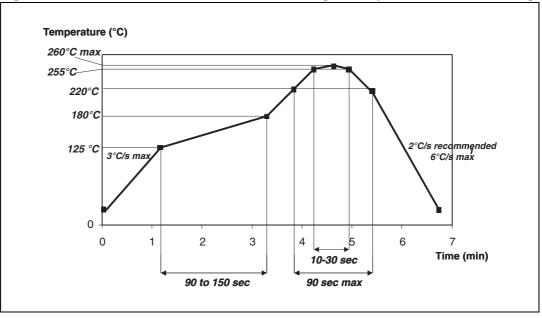
### 4.3 Placement

- 1. Manual positioning is not recommended.
- 2. It is recommended to use the lead recognition capabilities of the placement system, not the outline centering.
- 3. Standard tolerance of  $\pm$  0.05 mm is recommended.
- 4. 3.5 N placement force is recommended. Too much placement force can lead to squeezed out solder paste and cause solder joints to short. Too low placement force can lead to insufficient contact between package and solder paste that could cause open solder joints or badly centered packages.
- 5. To improve the package placement accuracy, a bottom side optical control should be performed with a high resolution tool.
- 6. For assembly, a perfect supporting of the PCB (all the more on flexible PCB) is recommended during solder paste printing, pick and place and reflow soldering by using optimized tools.

### 4.4 PCB design preference

- 1. To control the solder paste amount, the closed via is recommended instead of open vias.
- 2. The position of tracks and open vias in the solder area should be well balanced. The symmetrical layout is recommended, in case any tilt phenomena caused by asymmetrical solder paste amount due to the solder flow away.

### 4.5 Reflow profile



#### Figure 28. ST ECOPACK® recommended soldering reflow profile for PCB mounting



Minimize air convection currents in the reflow oven to avoid component movement.



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# 5 Package information

Epoxy meets UL94, V0

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at *www.st.com*.

Table 3.Micro QFN 1.45x1.00 6L dimensions

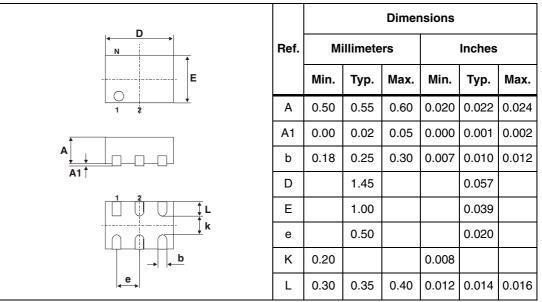
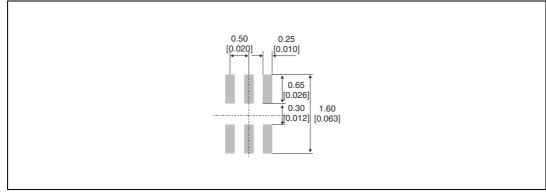


Figure 29. µQFN 6 leads footprint dimensions in mm [inches]



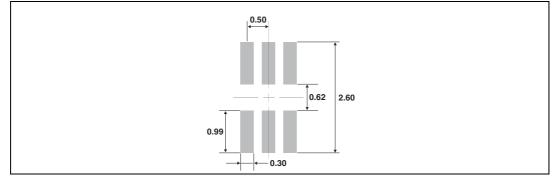
Note:

Product marking may be rotated by 90° for assembly plant differentiation. In no case should this product marking be used to orient the component for its placement on a PCB. Only pin 1 mark is to be used for this purpose.

		Dimensions					
→→→ <mark>▶</mark>  L1		М	illimete	ers		Inches	
		Min.	Тур.	Max.	Min.	Тур.	Max.
	А	0.45		0.60	0.018		0.024
	A3	0.08		0.18	0.003		0.007
b	b	0.17		0.34	0.007		0.013
	b1	0.19	0.27	0.34	0.007	0.011	0.013
	D	1.50		1.70	0.059		0.067
	Е	1.50		1.70	0.059		0.067
	E1	1.10		1.30	0.043		0.051
	е		0.50			0.020	
	L1		0.19			0.007	
भू में में	L2	0.10		0.30	0.004		0.012
<del>€</del> →	L3		0.10			0.004	

Table 4.SOT-666 dimensions





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# 6 Ordering information

#### Table 5.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
DVIULC6-2M6	T <sup>(1)</sup>	µQFN 6 leads	2.2 mg	3000	Tape and reel
DVIULC6-2P6	R	SOT-666	2.9 mg	3000	Tape and reel

1. The marking can be rotated by  $90^\circ$  to diferentiate assembly location

# 7 Revision history

#### Table 6. Document revision history

Date	Revision	Description of changes
06-May-2008	1	First issue.



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